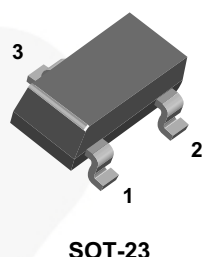


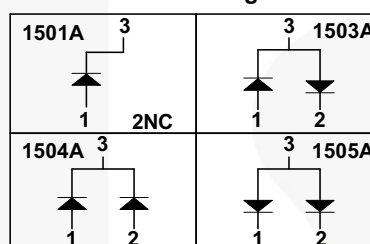


April 2016

MMBD1501A / MMBD1503A / MMBD1504A / MMBD1505A Small Signal Diodes



Connection Diagrams



Ordering Information

Part Number	Top Mark	Package	Packing Method
MMBD1501A	A11	SOT-23 3L	Tape and Reel, 7 inch Reel, 3k pieces
MMBD1503A	A13	SOT-23 3L	Tape and Reel, 7 inch Reel, 3k pieces
MMBD1503A_D87Z	A13	SOT-23 3L	Tape and Reel, 13 inch Reel, 10k pieces
MMBD1504A	A14	SOT-23 3L	Tape and Reel, 7 inch Reel, 3k pieces
MMBD1505A	A15	SOT-23 3L	Tape and Reel, 7 inch Reel, 3k pieces

Absolute Maximum Ratings^{(1), (2)}

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{RRM}	Maximum Repetitive Reverse Voltage	200	V
$I_{F(AV)}$	Average Rectified Forward Current	200	mA
I_{FSM}	Non-Repetitive Peak Forward Surge Current	Pulse Width = 1.0 second	1.0
		Pulse Width = 1.0 microsecond	2.0
T_{STG}	Storage Temperature Range	-55 to +150	$^\circ\text{C}$
T_J	Operating Junction Temperature	150	$^\circ\text{C}$

Notes:

1. These ratings are based on a maximum junction temperature of 150°C .
2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty-cycle operations.

MMBD1501A / MMBD1503A / MMBD1504A / MMBD1505A — Small Signal Diodes

Thermal Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Value	Unit
P_D	Power Dissipation	350	mW
$R_{\theta JA}$	Thermal Resistance, Junction-to-Ambient	357	$^\circ\text{C/W}$

Electrical Characteristics

Values are at $T_A = 25^\circ\text{C}$ unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
V_R	Breakdown Voltage	$I_R = 5.0\ \mu\text{A}$	200		V
V_F	Forward Voltage	$I_F = 1.0\ \text{mA}$	620	720	mV
		$I_F = 10\ \text{mA}$	720	830	mV
		$I_F = 50\ \text{mA}$	800	890	mV
		$I_F = 100\ \text{mA}$	830	930	mV
		$I_F = 200\ \text{mA}$	0.87	1.10	V
		$I_F = 300\ \text{mA}$	0.90	1.15	V
I_R	Reverse Current	$V_R = 125\ \text{V}$		1.0	nA
		$V_R = 125\ \text{V}, T_A = 150^\circ\text{C}$		3.0	μA
		$V_R = 180\ \text{V}$		10.0	nA
		$V_R = 180\ \text{V}, T_A = 150^\circ\text{C}$		5.0	μA
C_T	Total Capacitance	$V_R = 0, f = 1.0\ \text{MHz}$		4.0	pF

Typical Performance Characteristics

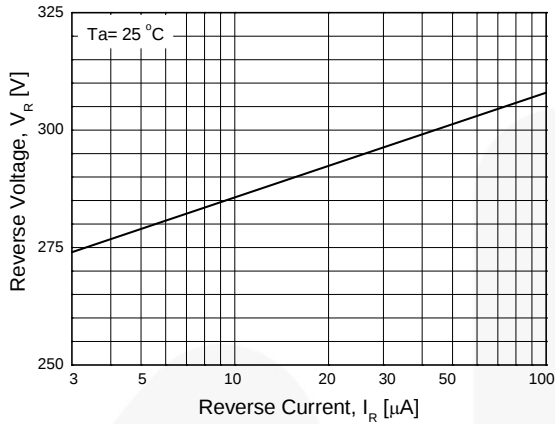


Figure 1. Reverse Voltage vs. Reverse Current
BV - 3.0 to 100 μ A

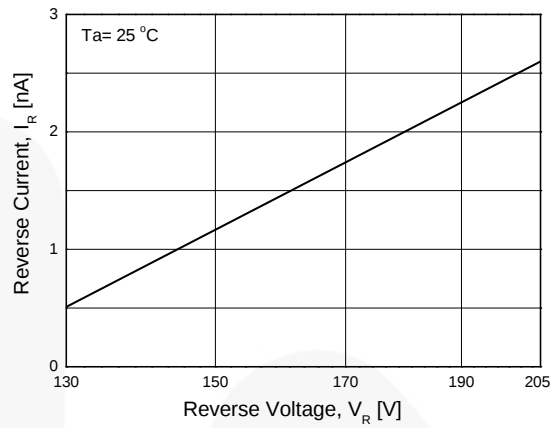


Figure 2. Reverse Current vs. Reverse Voltage
IR - 130 to 205 V

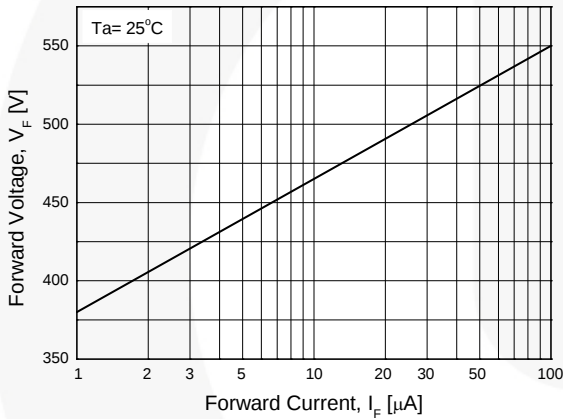


Figure 3. Forward Voltage vs. Forward Current
VF - 1 to 100 μ A

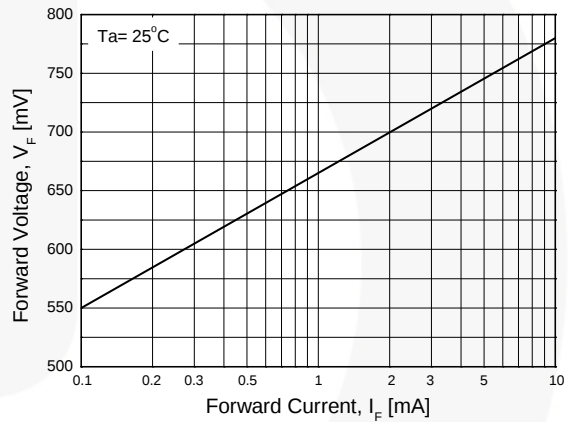


Figure 4. Forward Voltage vs. Forward Current
VF - 0.1 to 10 mA

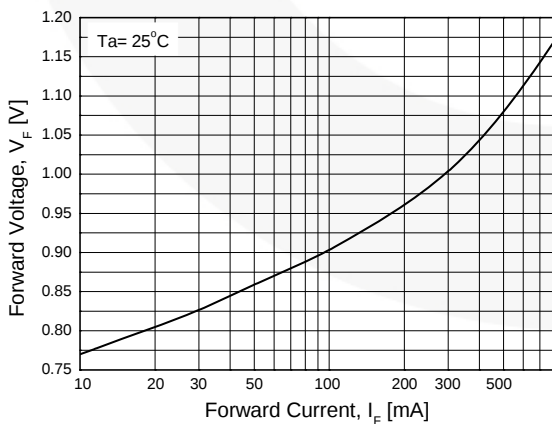


Figure 5. Forward Voltage vs. Forward Current
VF - 10 to 800 mA

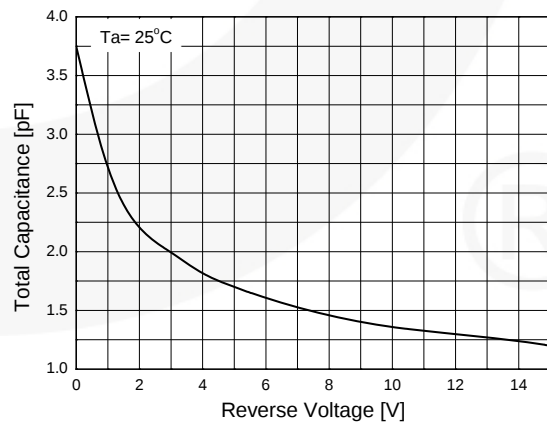


Figure 6. Total Capacitance vs. Reverse Voltage
VR - 0 to 15 V

Typical Performance Characteristics (Continued)

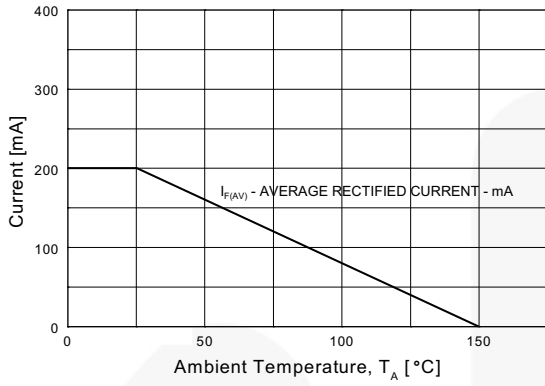


Figure 7. Average Rectified Current ($I_{F(AV)}$) vs. Ambient Temperature (T_A)

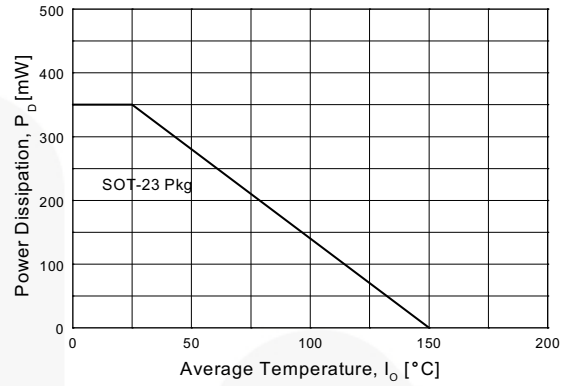
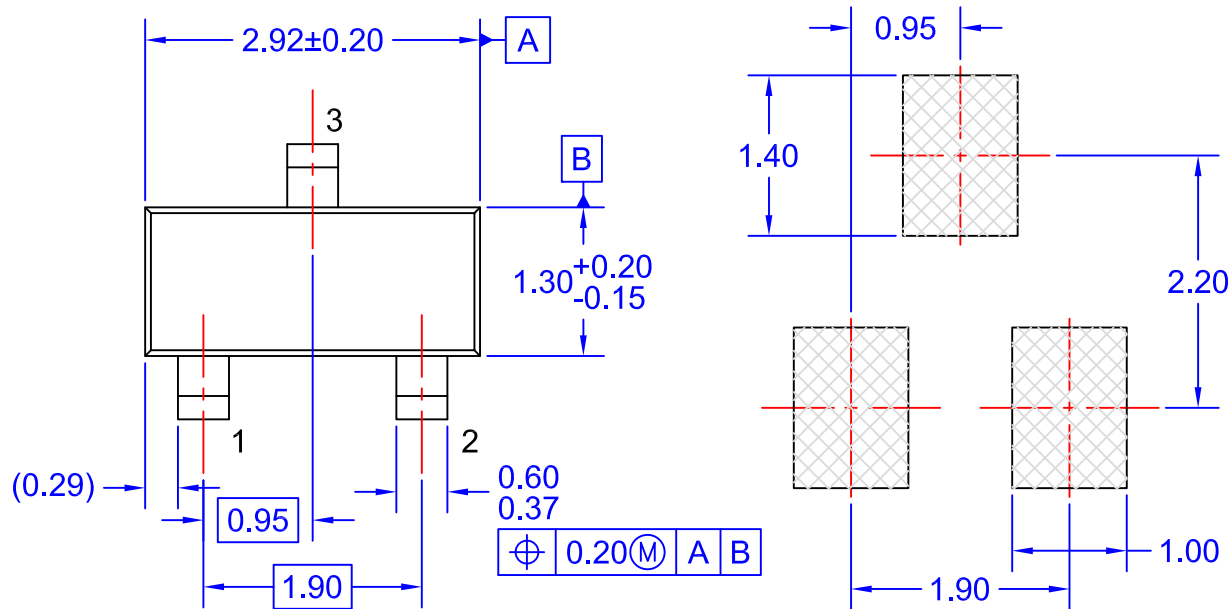
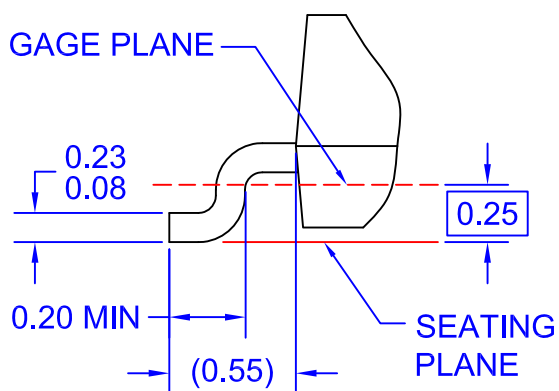
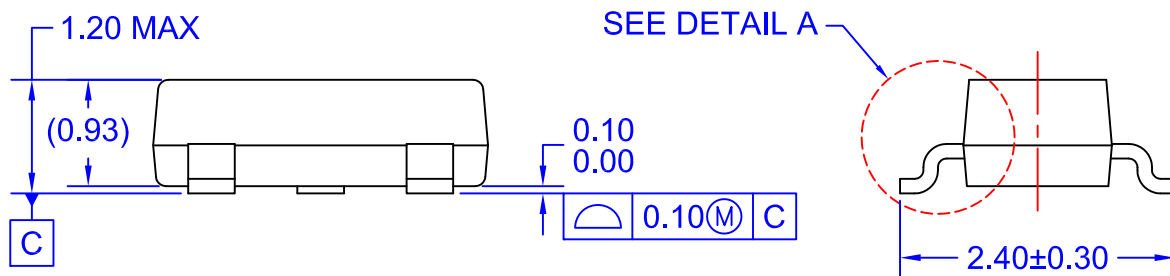


Figure 8. Power Derating Curve



LAND PATTERN
RECOMMENDATION



DETAIL A
SCALE: 2X

NOTES: UNLESS OTHERWISE SPECIFIED

- A) REFERENCE JEDEC REGISTRATION TO-236, VARIATION AB, ISSUE H.
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS ARE INCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR EXTRUSIONS.
- D) DIMENSIONING AND TOLERANCING PER ASME Y14.5M - 2009.
- E) DRAWING FILE NAME: MA03DREV12



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